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TOSHIBA Photocoupler Photo Relay

# TLP598GA

# Telecommunication Data Acquisition Measurement Instrumentation

The TOSHIBA TLP598GA consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo–MOS FET in a six lead plastic DIP package (DIP6).

The TLP598GA is a bi-directional switch which can replace mechanical relays in many applications.

- Peak off-state voltage: 400 V (min.)
- On-state current: 150 mA (max.) (A connection)
- On–state resistance: 12  $\Omega$  (max.) (A connection)
- Isolation voltage: 2500 Vrms (min.) (A connection)

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2.54±0.25

6 5 ¢

 $7.12 \pm 0.25$ 

 $0.5 \pm 0$ 

6.4土0.25

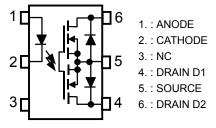
65 -0.25

11-7A8

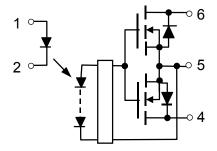
2±0.15

# Weight: 0.4 g

#### Pin Configuration (top view)



#### Schematic





 $7.62 \pm 0.25$ 

0.25

.85~8.80

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic		Symbol	Rating	Unit
	Forward current	lF	30	mA	
	Forward current derating (Ta ≥ 25°C)	ΔI <sub>F</sub> / °C	-0.3	mA / °C	
LED	Peak forward current (100 µs pulse, 100 pp	s)	IFP	1	А
	Reverse voltage	V <sub>R</sub>	5	V	
	Junction temperature	Тј	125	°C	
	Off-state output terminal voltage	V <sub>OFF</sub>	400	V	
	On-state RMS current	A connection		150	
		B connection	ION	200	mA
ctor		C connection		300	
Detector	On–state current derating (Ta ≥ 25°C)	A connection	ΔI <sub>ON</sub> / °C	-1.5	
		B connection		-2.0	mA / °C
		C connection		-3.0	
	Junction temperature	Тј	125	°C	
Storage temperature range			T <sub>stg</sub>	-55~125	°C
Oper	ating temperature range	T <sub>opr</sub>	-40~85	°C	
Lead	soldering temperature (10 s)	T <sub>sol</sub>	260	°C	
Isola	tion voltage (AC, 1 min., R.H. ≤ 60%)	BVS	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

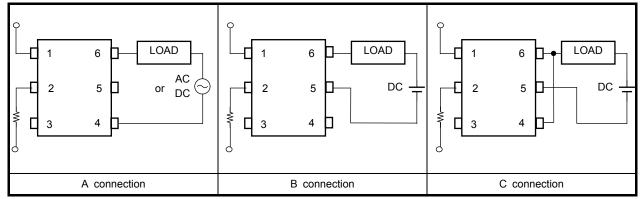
(Note 2): Device considered a two-terminal device: Pins 1, 2 and 3 shorted together, and pins 4, 5 and 6 shorted together.

#### **Recommended Operating Conditions**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V <sub>DD</sub>	_	—	320	V
Forward current	١ <sub>F</sub>	5	7.5	20	mA
On-state current (A connection)	I <sub>ON</sub>	—	_	150	mA
Operating temperature	T <sub>opr</sub>	-20		80	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

#### **Circuit Connections**



## Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.18	1.33	1.48	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz	_	30	_	pF
ector	Off-state current	IOFF	V <sub>OFF</sub> = 400 V	_	_	1	μA
Detector	Capacitance	C <sub>OFF</sub>	V = 0, f = 1 MHz	_	_	_	pF

# Coupled Electrical Characteristics (Ta = 25°C)

Cha	aracteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current		I <sub>FT</sub>	I <sub>ON</sub> = 150 mA	—	1	3	mA
	A connection	4 –	I <sub>ON</sub> = 150 mA, I <sub>F</sub> = 5 mA	—	8	12	
On-state resistance	B connection		I <sub>ON</sub> = 200 mA, I <sub>F</sub> = 5 mA	—	4	6	Ω
	C connection		I <sub>ON</sub> = 300 mA, I <sub>F</sub> = 5 mA	—	2	3	

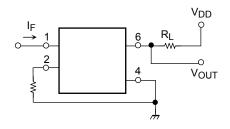
#### Isolation Characteristics (Ta = 25°C)

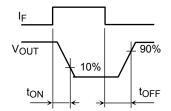
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V <sub>S</sub> = 0, f = 1 MHz	—	0.8	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≤ 60%	$5  imes 10^{10}$	10 <sup>14</sup>	_	Ω
		AC, 1 minute	2500	_	_	Vrms
Isolation voltage	BVS	AC, 1 second (in oil)	_	5000	_	vinis
		DC, 1 minute (in oil)	—	5000	_	V <sub>DC</sub>

## Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Turn-on time	t <sub>ON</sub>	V <sub>DD</sub> = 20 V, R <sub>L</sub> = 200 Ω	_	0.3	1.0	ms
		$I_F = 5 \text{ mA}$ (Note 3)		0.2	1.0	1115

(Note 3): Switching time test circuit





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30

10

3

10<sup>-3</sup>

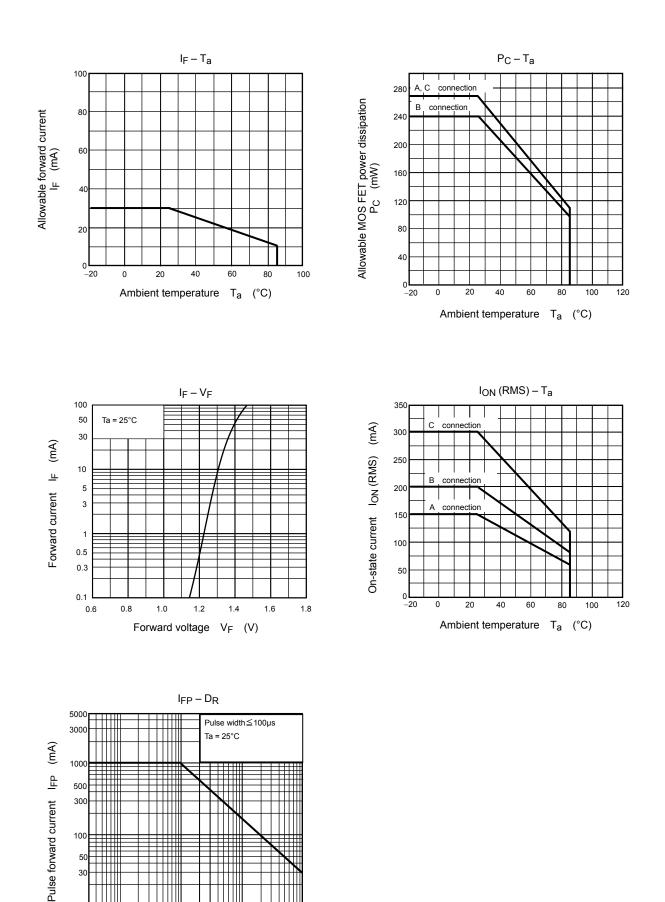
3

 $10^{-2}$ 

3

Duty cycle ratio DR

 $10^{-1}$ 



10<sup>0</sup>

3

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20070701-EN

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